

Precision Adjustable Current-Limited, Power-Distribution Switches

Check for Samples: [TPS2554](#), [TPS2555](#)

FEATURES

- Meets USB Current-Limiting Requirements
- Adjustable Current Limit, 500 mA to 2.5 A (typ)
- Two Independently-Settable, Current-Limit Thresholds
- Fast Overcurrent Response - 1.5 μ s (typ)
- 73-m Ω High-Side MOSFET
- 3.8- μ A Maximum Standby Supply Current
- PowerPAD™ Thermal Management
- Automatic Output Discharge when Disabled
- Both High-Enable (TPS2554) and Low-Enable (TPS2555) Versions Available

APPLICATIONS

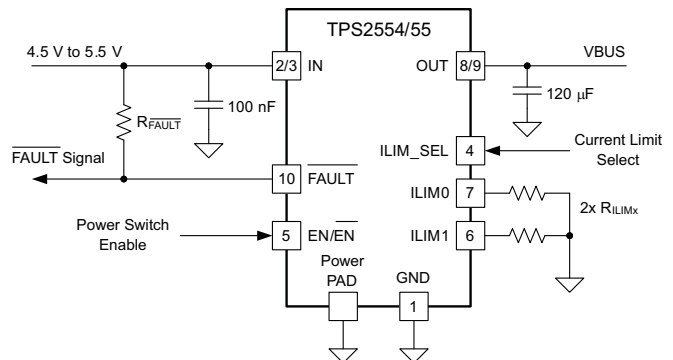
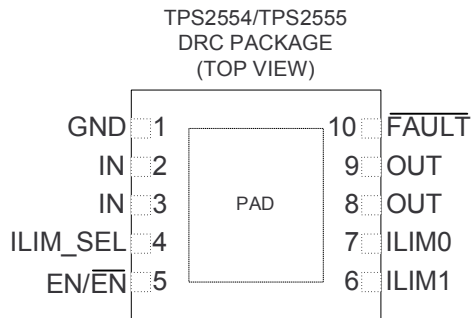
- USB Ports/Hubs
- Digital TV
- Set-Top Boxes
- VOIP Phones

DESCRIPTION

The TPS2554/55 power-distribution switches are intended for applications where precision current limiting is required or heavy capacitive loads and short circuits are encountered. These devices offer a programmable current-limit threshold between 500 mA and 2.5 A (typ) via an external resistor.

TPS2554/55 devices limit the output current to a safe level by switching into a constant-current mode when the output load exceeds the current-limit threshold. The **FAULT** logic output asserts low during overcurrent and over-temperature conditions.

TPS2554/55 DRC Package and Typical Application Diagram



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾ ⁽²⁾

		VALUE	UNIT
Voltage range on IN, OUT, EN or $\overline{\text{EN}}$, ILIM0, ILIM1, ILIM_SEL, $\overline{\text{FAULT}}$		–0.3 to 7	V
Voltage range from IN to OUT		–7 to 7	
I_{OUT}	Continuous output current	Internally limited	
Continuous total power dissipation		Internally limited	
Continuous $\overline{\text{FAULT}}$ sink current		25	mA
ILIM source current		Internally limited	
ESD	HBM	2	kV
	CDM	500	V
T_J	Maximum junction temperature	–40 to OTSD2 ⁽³⁾	°C
T_{stg}	Storage temperature range	–65 to 150	

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Voltages are referenced to GND unless otherwise noted.

(3) Ambient over-temperature shutdown threshold.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{IN}	Input voltage, IN	4.5	5.5	V
$V_{\text{EN}}, V_{\overline{\text{EN}}}, \text{ILIM_SEL}$	Logic-level inputs	0	5.5	
I_{OUT}	Continuous output current, OUT	0	2.5	A
T_J	Operating virtual junction temperature	–40	125	°C
R_{ILIM}	Recommended resistor limit range	16.9	750	kΩ

THERMAL INFORMATION

THERMAL METRIC ⁽¹⁾		TPS2554/TPS2555	UNITS
		DRC	
		14 PINS	
θ_{JA}	Junction-to-ambient thermal resistance ⁽²⁾	45.9	°C/W
θ_{JCTop}	Junction-to-case (top) thermal resistance ⁽³⁾	53.4	
θ_{JB}	Junction-to-board thermal resistance ⁽⁴⁾	21.4	
ψ_{JT}	Junction-to-top characterization parameter ⁽⁵⁾	1.0	
ψ_{JB}	Junction-to-board characterization parameter ⁽⁶⁾	21.6	
θ_{JCbott}	Junction-to-case (bottom) thermal resistance ⁽⁷⁾	5.9	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

ELECTRICAL CHARACTERISTICS

Conditions are $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$ unless otherwise noted V_{EN} (if TPS2554) = $V_{\text{IN}} = 5\text{ V}$, $\overline{V_{\text{EN}}}$ (if TPS2555) = 0 V , $R_{\text{FAULT}} = 10\text{ k}\Omega$, $R_{\text{ILIM0}} = 210\text{ k}\Omega$, $R_{\text{ILIM1}} = 20\text{ k}\Omega$, $\text{ILIM_SEL} = 0\text{ V}$ unless otherwise noted. Positive currents are into pins. Typical values are at 25°C . All voltages are with respect to GND unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Power Switch							
R _{DS(on)}	Static drain-source on-state resistance	I _{OUT} = 2 A, V _{ILIM_SEL} = Logic HI			73	120	mΩ
		I _{OUT} = 100 mA, V _{ILIM_SEL} = Logic LO			73	120	
		-40 °C ≤ T _A = T _J ≤ 85 °C, I _{OUT} = 2 A, V _{ILIM_SEL} = Logic HI			73	105	
		T _A = T _J = 25 °C, I _{OUT} = 2 A, V _{ILIM_SEL} = Logic HI			73	84	
t _r	Rise time, output	C _L = 1 μF, R _L = 100 Ω			1	1.5	ms
t _f	Fall time, output	C _L = 1 μF, R _L = 100 Ω		0.2		0.5	
R _{DIS}	OUT discharge resistance			400	500	630	Ω
I _{REV}	Reverse leakage current	V _{OUT} = 5.5 V, V _{IN} = V _{EN} = 0 V or V _{OUT} = V _{EN} = 5.5 V, V _{IN} = 0 V, T _J = 25 °C			0	1	μA
Enable Input EN (TPS2554), $\overline{\text{Enable}}$ Input $\overline{\text{EN}}$ (TPS2555)							
V _{EN} , $\overline{V_{\text{EN}}}$	EN, $\overline{\text{EN}}$ pin threshold, falling			0.9	1.1	1.65	V
V _{EN_HYS}	EN, $\overline{\text{EN}}$ Hysteresis				200		mV
I _{EN} , $\overline{I_{\text{EN}}}$	Input current	V _{EN} , $\overline{V_{\text{EN}}}$ = 0 V or 5.5 V		-0.5		0.5	μA
t _{ON}	Turn-on time	C _L = 1 μF, R _L = 100 Ω			3.4	5	ms
t _{OFF}	Turn-off time	C _L = 1 μF, R _L = 100 Ω			1.7	3	
Current Limit							
V _{ILIM_SEL}	ILIM_SEL threshold, falling			0.9	1.1	1.65	V
V _{ILIM_HYS}	I _{ILIM_SEL} Hysteresis				200		mV
	ILIM_SEL input current	V _{ILIM_SEL} = 0 V or 5.5 V		-0.5		0.5	μA
I _{SHORT}	Maximum DC output current from IN to OUT	V _{ILIM_SEL} = Logic LO	R _{ILIM0} = 210 kΩ	185	230	265	mA
			R _{ILIM0} = 100 kΩ	420	480	530	
		V _{ILIM_SEL} = Logic HI	R _{ILIM1} = 20 kΩ	2150	2430	2650	
			R _{ILIM1} = 16.9 kΩ	2550	2840	3100	
t _{IOS}	Response time to short circuit	V _{IN} = 5.0 V			1.5		μs
Supply Current							
I _{CCL}	Supply current, switch disabled	V _{EN} = 0 V, $\overline{V_{\text{EN}}} = V_{\text{IN}}$; OUT grounded; -40 °C ≤ T _J ≤ 85 °C			0.1	3.8	μA
I _{CCH}	Supply current, operating	V _{EN} = 0 V, $\overline{V_{\text{EN}}} = V_{\text{IN}}$			90	115	
			V _{ILIM_SEL} = Logic HI		110	135	
Undervoltage Lockout							
V _{UVLO}	Low-level input voltage, IN	V _{IN} rising		3.9	4.1	4.3	V
	Hysteresis, IN				100		mV
FAULT							
	Output low voltage, $\overline{\text{FAULT}}$	I $\overline{\text{FAULT}}$ = 1 mA				100	mV
	Off-state leakage	V $\overline{\text{FAULT}}$ = 5.5 V				1	μA
	$\overline{\text{FAULT}}$ deglitch	$\overline{\text{FAULT}}$ assertion or negation due to overcurrent condition		5	8.5	12	ms
Thermal Shutdown							
	Thermal shutdown threshold			155			°C
	Thermal shutdown threshold in current-limit			135			
	Hysteresis				10		

Parameter Measurement Information

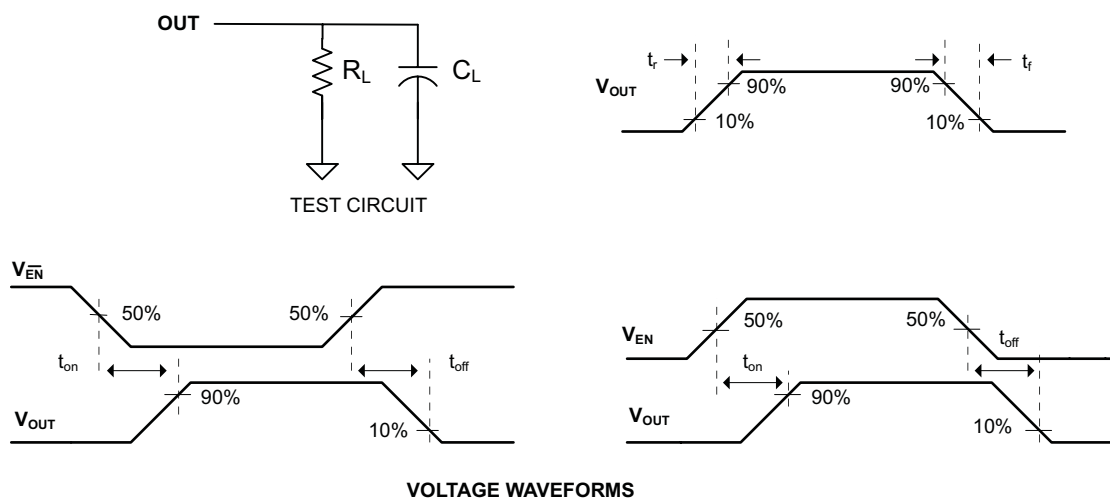


Figure 1. Test Circuit and Voltage Waveforms

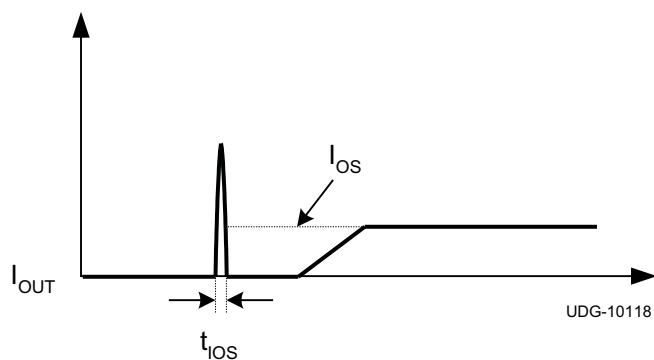


Figure 2. Response Time to Short-Circuit Waveform

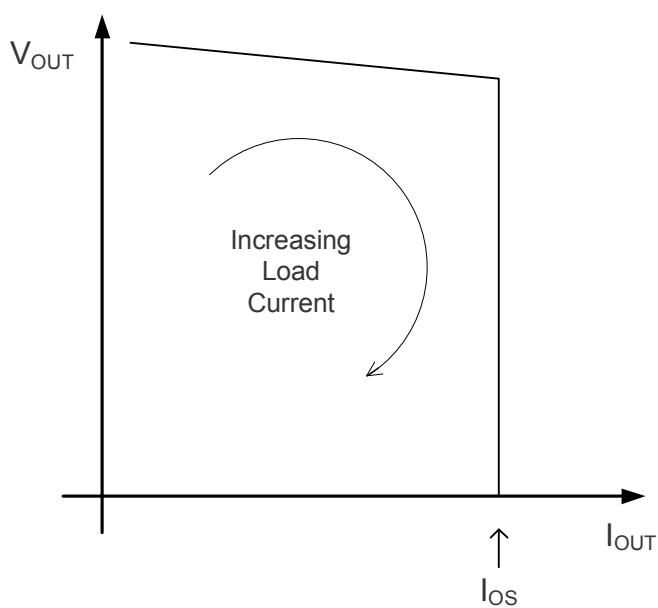


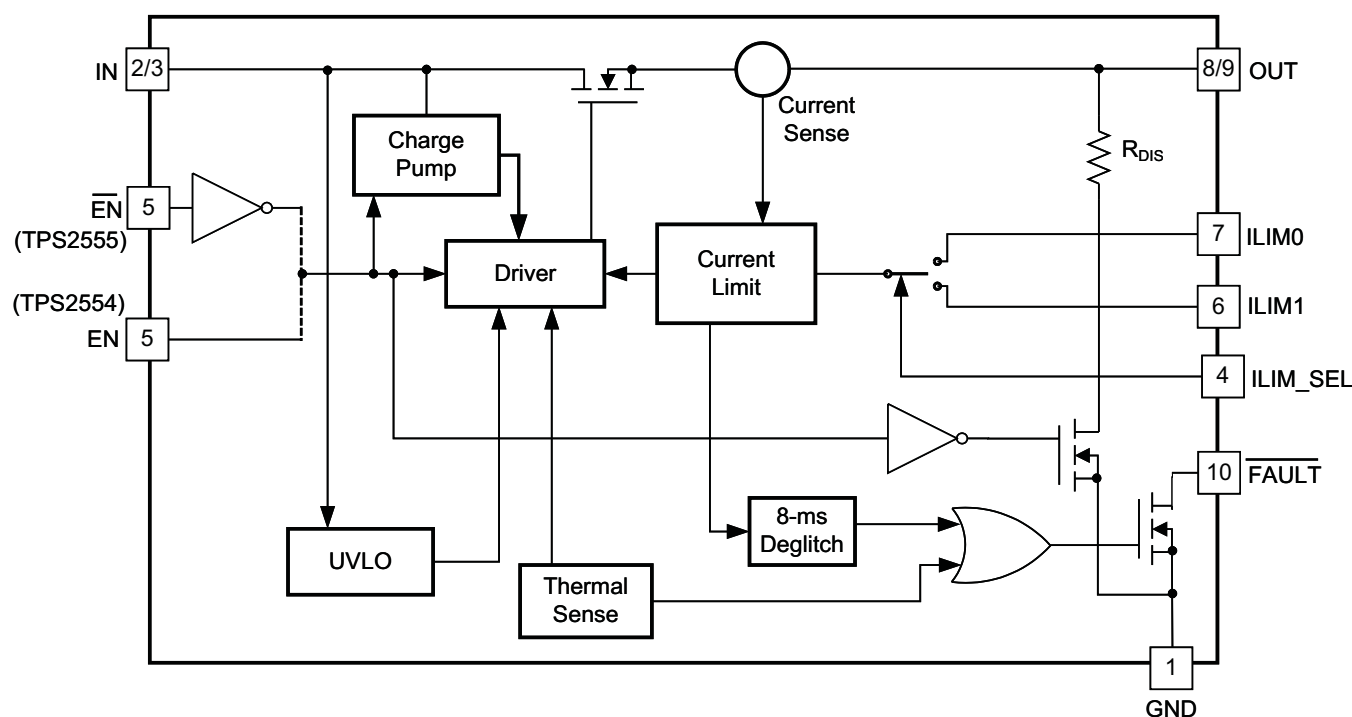
Figure 3. Output Voltage vs Output Current Behavior

DEVICE INFORMATION

Pin Functions

NAME	PIN		I/O	DESCRIPTION
	TPS2554	TPS2555		
EN	5	-	I	Enable input, logic high turns on power switch (TPS2554).
$\overline{\text{EN}}$	-	5	I	Enable input, logic low turns on power switch (TPS2555).
GND	1	1		Ground connection; connect externally to PowerPAD™.
IN	2, 3	2, 3	I	Input voltage; connect a 100-nF, or greater, ceramic capacitor from IN to GND as close to the device as possible.
$\overline{\text{FAULT}}$	10	19	O	Active-low, open-drain output, asserted during overcurrent or over-temperature conditions.
OUT	8, 9	8, 9	O	Power-switch output
ILIM0	7	7	I	External resistor used to set current-limit threshold when ILIM_SEL = LO
ILIM1	6	6	I	External resistor used to set current-limit threshold when ILIM_SEL = HI
ILIM_SEL	4	4	I	Logic-level input that selects between ILIM0 and ILIM1 current-limit threshold setting
PowerPAD™	–	–		Internally connected to GND; used to heat-sink the device to the circuit board traces. Connect PowerPAD™ to GND pin externally.

TPS2554/TPS2555 Functional Block Diagram



TYPICAL CHARACTERISTICS

In UVLO Rising
vs
Temperature

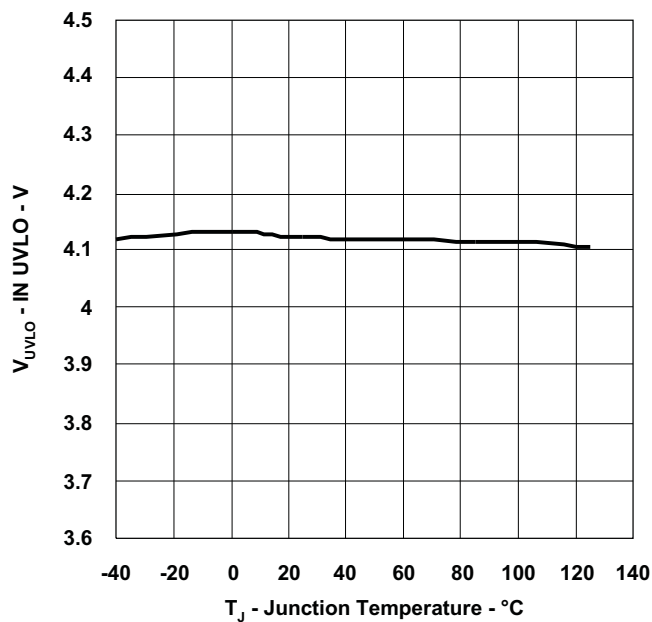


Figure 4.

Supply Current - Disabled
vs
Temperature

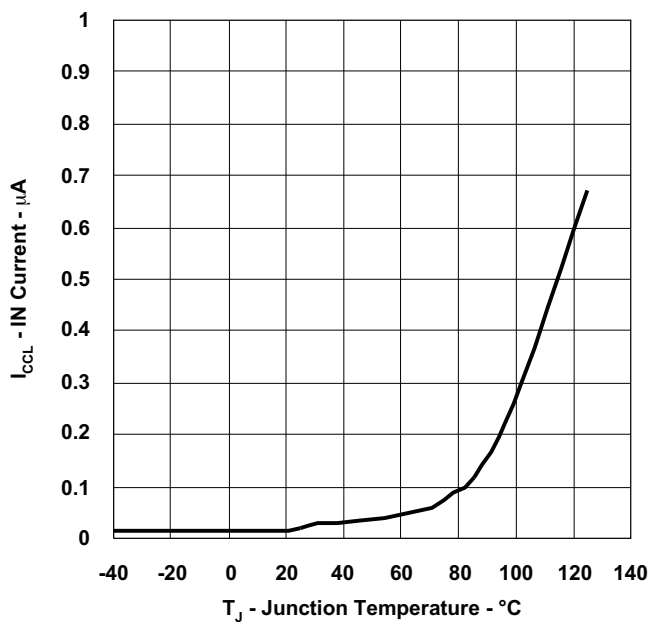


Figure 5.

Supply Current
vs
Temperature

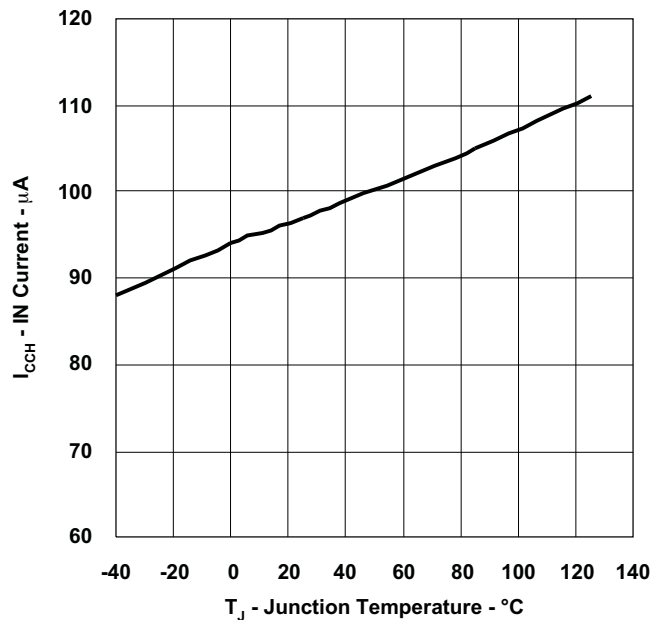


Figure 6.

Current Limit
vs
Current Limit Resistance

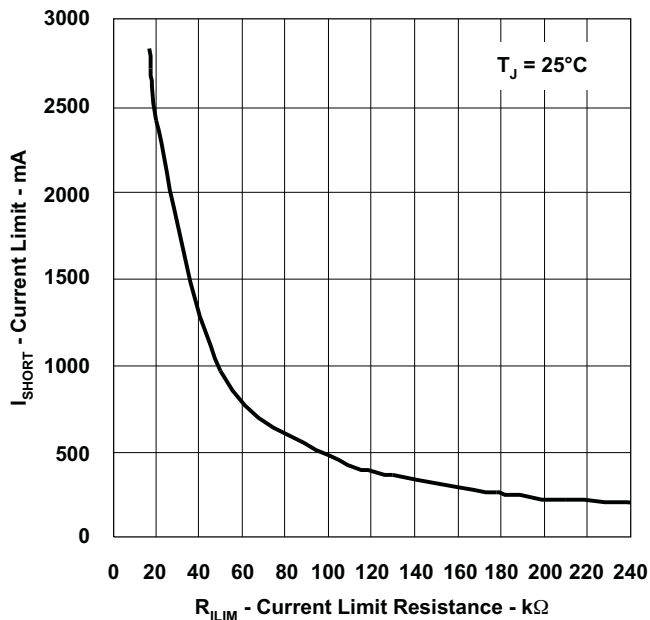
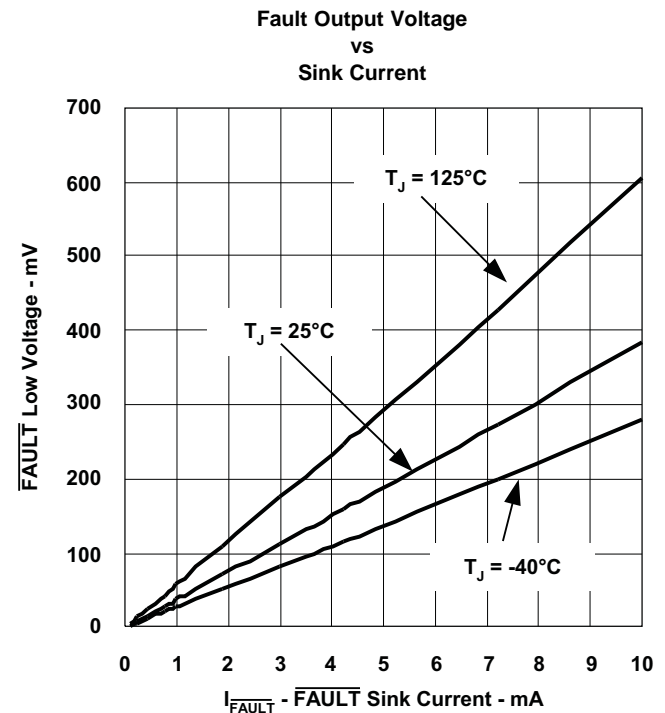
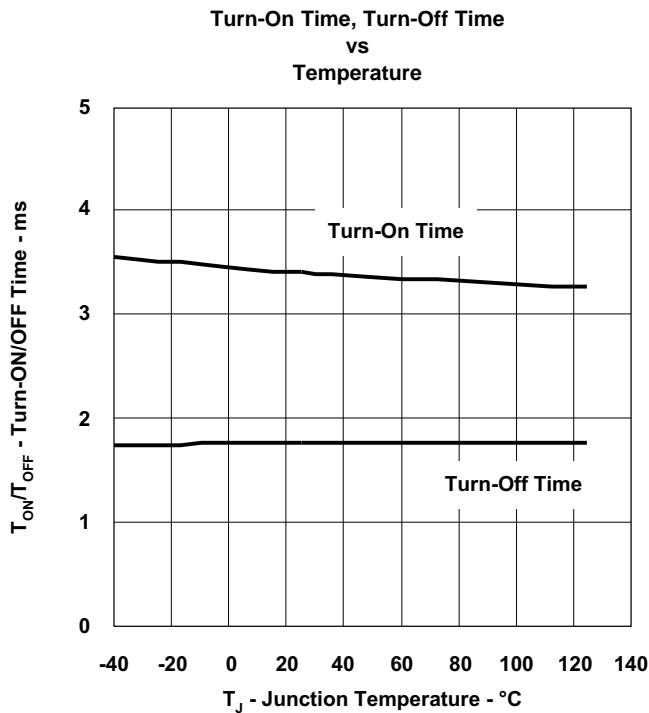
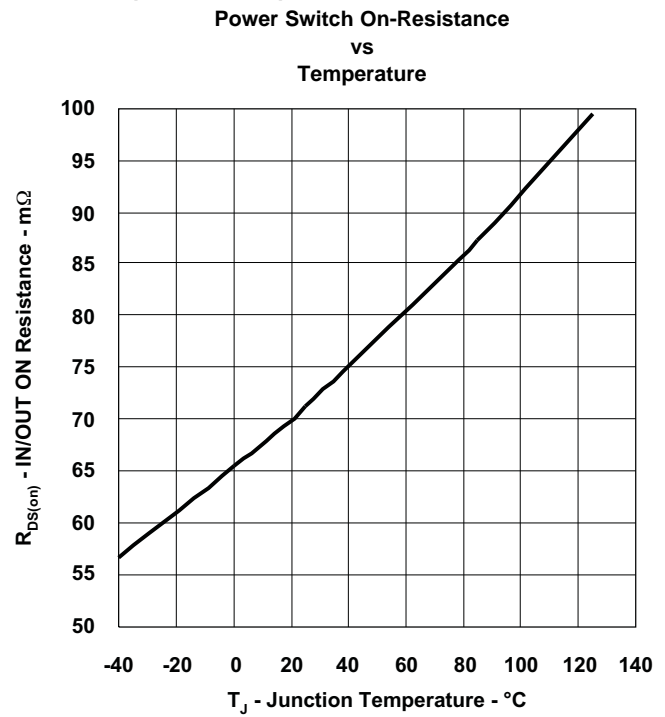
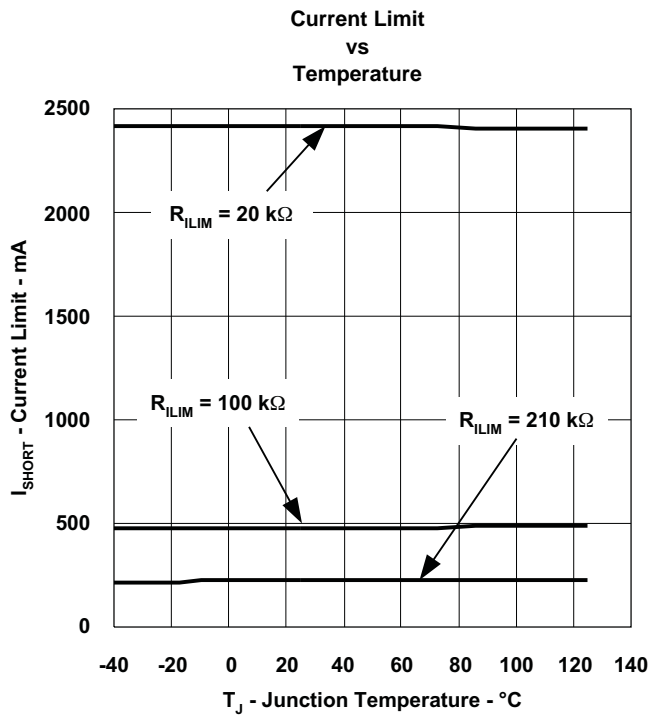


Figure 7.

TYPICAL CHARACTERISTICS (continued)



TYPICAL CHARACTERISTICS (continued)

EN Threshold Falling
vs
Temperature

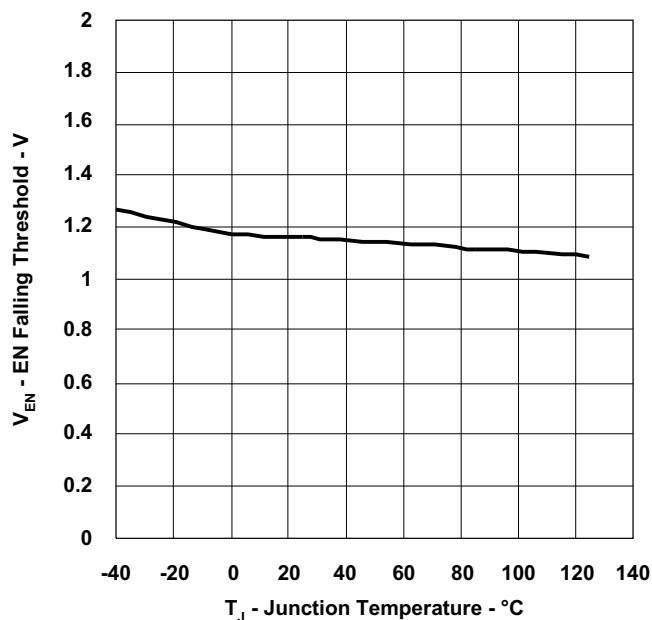


Figure 12.

Response to a Short Circuit
(following assertion of enable)

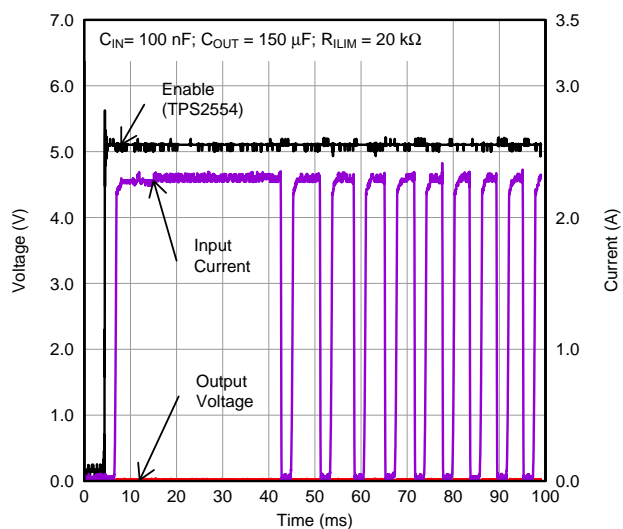


Figure 13.

Response to a Short Circuit
(apply input voltage with output shorted)

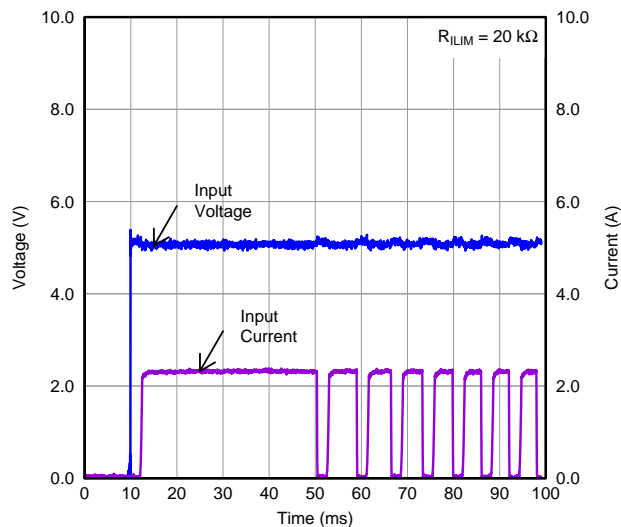


Figure 14.

Response to a Short Circuit
(apply input voltage with output shorted)

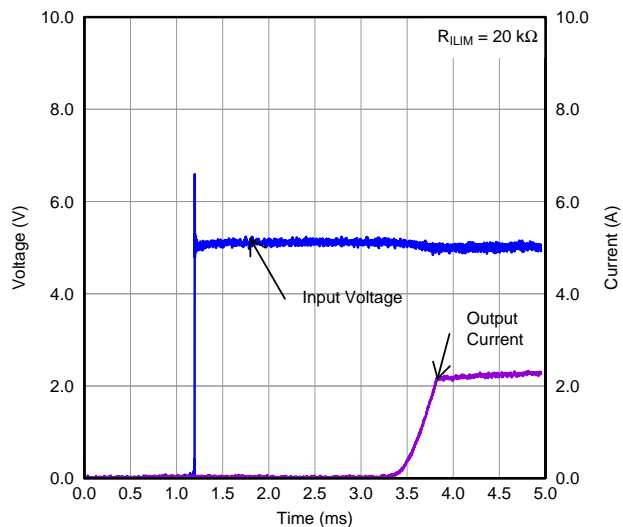


Figure 15.

TYPICAL CHARACTERISTICS (continued)

**Response to a Short Circuit
(from a no-load condition)**

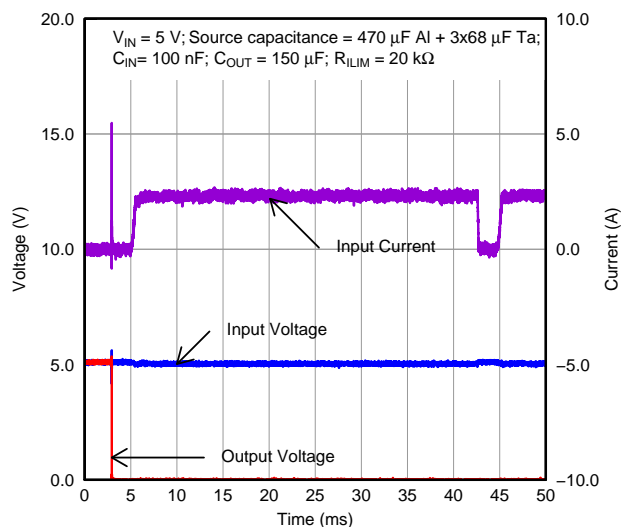


Figure 16.

**Response to a Short Circuit
(from a no-load condition)**

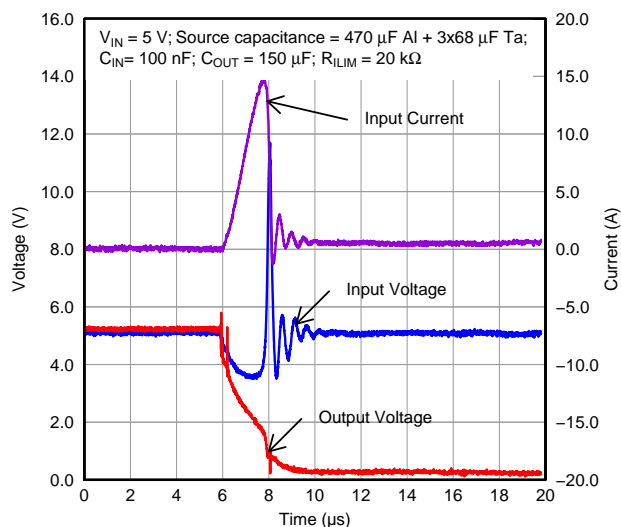


Figure 17.

DETAILED DESCRIPTION

Overview

The TPS2554/55 is a current-limited, power-distribution switch using an internal N-channel MOSFET as a switch for applications where short circuits or heavy-capacitive loads will be encountered. This device allows the user to program two independent current-limit thresholds between 500 mA and 2.5 A (typ) via two external resistors. The ILIM_SEL pin allows the user to select one current limit or the other. This device incorporates an internal charge pump and the gate-drive circuitry necessary to drive the N-channel MOSFET. The charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The driver controls the gate voltage of the power switch. The TPS2554/55 family limits the output current to the programmed current-limit threshold I_{LIM0} or I_{LIM1} during an overcurrent or short-circuit event by reducing the charge-pump voltage driving the N-channel MOSFET and operating it in the linear range of operation. This necessarily results in a reduction in the output voltage at OUT. Exposure to an overload condition leads directly to heat dissipation in the internal MOSFET. The MOSFET is protected thermally such that it will shut off when it gets too hot. The TPS2554/55 will automatically restart following cooling of the device.

Overcurrent Conditions

The TPS2554/55 responds to overcurrent conditions by limiting the output current to the short-circuit current set by R_{ILIM0} or R_{ILIM1} , whichever is selected at the ILIM_SEL pin. When an overcurrent condition is detected the device maintains a constant output current, and the output voltage reduces accordingly. Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present when the device is powered-up or enabled. The output voltage is held near zero potential with respect to ground and the TPS2554/55 ramps the output current to the selected output current, I_{LIM0} or I_{LIM1} . The TPS2554/55 will limit the current to the selected limit until the overload condition is removed or heating of the internal MOSFET forces a shutdown. (Following thermal shutdown the TPS2554/55 cools and another start-up attempt occurs automatically.)

The second condition is when a short circuit, partial short circuit, or transient overload occurs while the device is enabled and powered on. In response to the load transient the output current will typically overshoot the selected current limit during t_{OS} as the TPS2554/55 turns off the pass device. Then, the current-sense amplifier will recover and the output current will be maintained at the selected current limit. As in the previous case, the TPS2554/55 will maintain the current limit until the overload condition is removed or the device begins to thermal cycle.

The TPS2554/55 thermal cycles if an overload condition is present long enough to activate thermal limiting in any of the above cases. The device turns off when the junction temperature exceeds 135°C (min) while in current limit. The device remains off until the junction temperature cools 20°C (typ) and then restarts. The TPS2554/55 cycles on/off until the overload is removed.

Current-Limit Thresholds

The TPS2554/5 has two independent current-limit thresholds that are each programmed externally with a resistor. The following equation programs the typical current-limit threshold:

$$I_{SHORT} = \frac{48000}{R_{ILIMx}}$$

where

- I_{SHORT} = Current-limit threshold, mA
 - R_{ILIM} = Resistance at ILIMx pin, kΩ
- (1)

R_{ILIMx} corresponds to R_{ILIM0} when ILIM_SEL is logic LO and to R_{ILIM1} when ILIM_SEL is logic HI. The ILIM_SEL pin allows the system to digitally select between two current-limit thresholds, which is useful, for example, in end equipment that may require a lower setting when powered from batteries versus wall adapters.

FAULT Response

The $\overline{\text{FAULT}}$ open-drain output is asserted low during an overcurrent or over-temperature condition. The TPS2554/55 asserts the $\overline{\text{FAULT}}$ signal until the fault condition is removed and the device resumes normal operation. The TPS2554/55 is designed to eliminate false $\overline{\text{FAULT}}$ reporting by using an internal delay "degitch" circuit for overcurrent conditions (9 ms typical) without the need for external circuitry. This ensures that $\overline{\text{FAULT}}$ is not accidentally asserted due to normal operation such as starting into a heavy capacitive load. The deglitch circuitry delays entering and leaving current-limit-induced fault conditions. The $\overline{\text{FAULT}}$ signal is not deglitched when the MOSFET is disabled due to an over-temperature condition, but it is deglitched after the device has cooled and begins to turn on. This unidirectional deglitch feature prevents $\overline{\text{FAULT}}$ oscillation during an over-temperature event.

Undervoltage Lockout (UVLO)

The Undervoltage Lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turn-on threshold (4.1 V, nominal). Built-in hysteresis prevents unwanted on/off cycling due to input-voltage droop during turn on.

Enable (EN OR $\overline{\text{EN}}$)

The logic enable controls the power switch and device supply current. The supply current is reduced to less than 3.8 μA when a logic low is present on EN (TPS2554) or when a logic high is present on $\overline{\text{EN}}$ (TPS2555). A logic high input on EN or a logic low input on $\overline{\text{EN}}$ enables the driver, control circuits, and power switch. The enable input is compatible with both TTL and CMOS logic levels.

Output Discharge

When the output is disabled through either the EN (TPS2554) or $\overline{\text{EN}}$ (TPS2555) pin or by an over-temperature shutdown the OUT pin is discharged internally through a MOSFET. Nominal MOSFET resistance (R_{DIS}) is 500 Ω .

Thermal Sense

The TPS2554/55 self protects by using two independent thermal-sensing circuits that monitor the operating temperature of the power switch and will disable operation if the temperature exceeds recommended operating conditions. The TPS2554/55 device operates in constant-current mode during an overcurrent condition thereby increasing the voltage drop across the MOSFET power switch. The power dissipation in the package increases with the voltage drop across the power switch, thereby causing the junction temperature to rise during an overcurrent condition. The first thermal sensor turns off the power switch when the die temperature exceeds 135°C (min) and the part is in current limit. Hysteresis is built into the thermal sensor, and the switch turns on after the device has cooled approximately 20°C. The TPS2554/55 continues to cycle off and on until the fault is removed.

The TPS2554/55 also has a second ambient thermal sensor. The ambient thermal sensor turns off the power switch when the die temperature exceeds 155°C (min) regardless of whether the power switch is in current limit and will turn on the power switch back on after the device has cooled approximately 20°C. The TPS2554/55 will continue to cycle off and on until the fault is removed.

APPLICATION INFORMATION

Input and Output Capacitance

Capacitance added to the input and output of the TPS2554/55 improves the performance of the device; the actual capacitance should be optimized for the particular application. For all applications, a 100 nF or greater ceramic bypass capacitor between IN and GND is recommended as close to the device as possible for local noise decoupling. This precaution reduces ringing on the input due to power-supply transients. Additional input capacitance may be needed on the input to prevent voltage overshoot from exceeding the absolute-maximum voltage of the device during heavy transient conditions. This is especially important during bench testing when long, inductive cables are used to connect the evaluation board to the bench power supply.

Output capacitance is not required for proper operation of the TPS2554/55, but placing a high-value electrolytic capacitor on the output pin is recommended when large transient currents are expected on the output.

Programming the Current-Limit Threshold

Two overcurrent thresholds are user-programmable via two external resistors. The recommended 1% resistor range for R_{ILIMx} is $16.9\text{ k}\Omega \leq R_{ILIM} \leq 750\text{ k}\Omega$ to ensure stability of the internal regulation loop. Best accuracy is obtained with R_{ILIMx} values less than 210 k Ω . Many applications require that the minimum current limit is above a certain current level or that the maximum current limit is below a certain current level, so it is important to consider the tolerance of the overcurrent threshold when selecting a value for R_{ILIMx} . The following equations approximate the resulting overcurrent threshold for a given external resistor value, R_{ILIMx} . Consult the Electrical Characteristics table for specific current-limit settings. Printed-circuit-board traces routing the R_{ILIMx} resistor to the TPS2554/55 should be as short as possible to reduce parasitic effects on the current-limit accuracy.

The equations and the graph below can be used to estimate the minimum and maximum variation of the current-limit threshold for a predefined resistor value. This variation is an approximation only and does not take into account, for example, the resistor tolerance. For examples of more-precise variation of I_{SHORT} refer to the current-limit section of the Electrical Characteristics table.

$$I_{SHORT} = \frac{48000}{R_{ILIMx}} \quad (2)$$

$$I_{SHORT_min} = \frac{48000}{R_{ILIMx}^{1.037}} \quad (3)$$

$$I_{SHORT_max} = \frac{48000}{R_{ILIMx}^{0.962}} \quad (4)$$

- I_{SHORT} = Current-limit threshold, mA
- R_{ILIM} = Resistance at ILIMx pin, k Ω

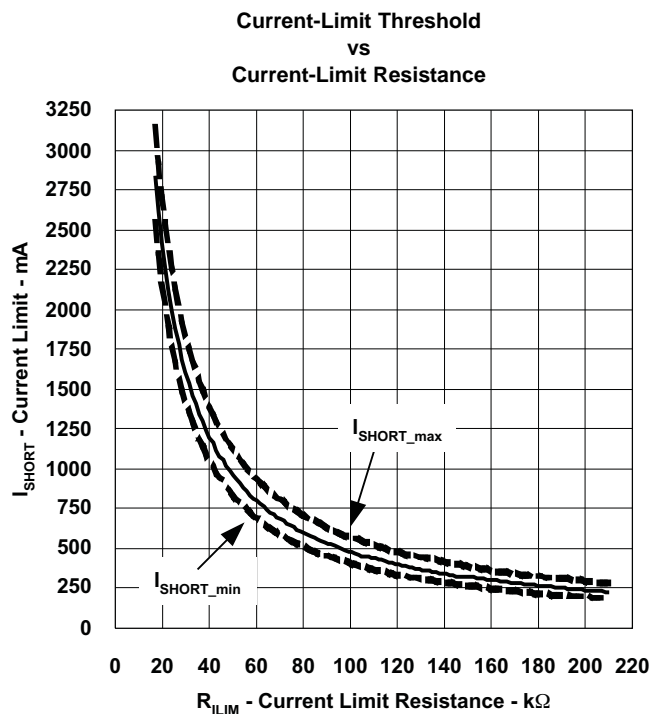


Figure 18.

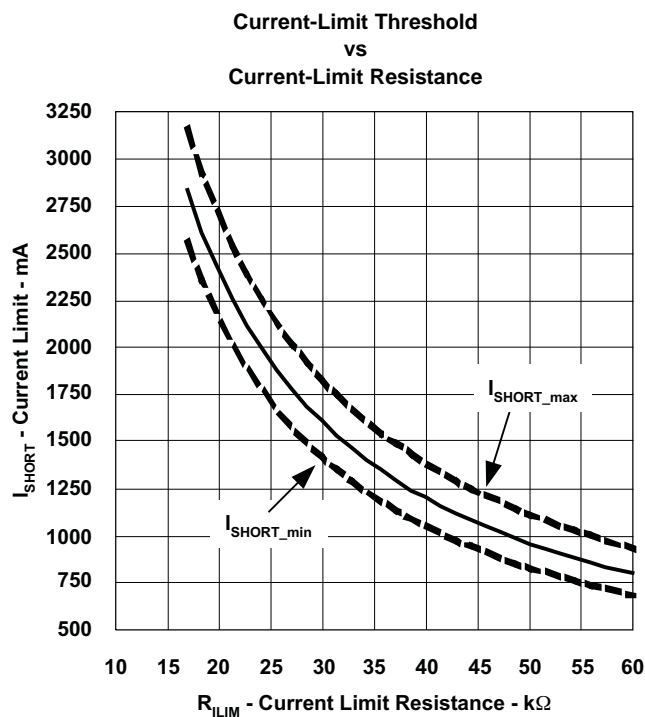


Figure 19.

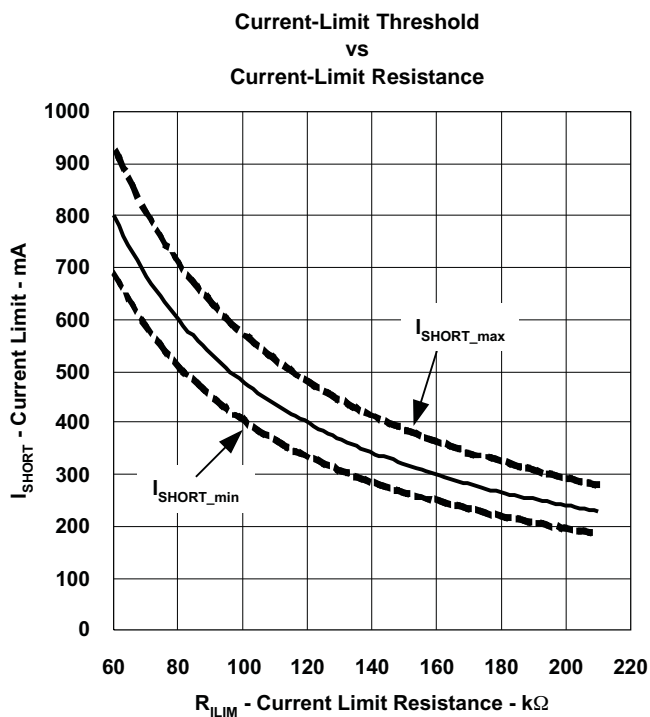


Figure 20.

Current Limit Setpoint Example

In the following example, choose the ILIM resistor to ensure that the TPS2554/55 does not trip off under worst-case conditions of ILIM and resistor tolerance (assume 1% initial-plus-temperature resistor tolerance). For this example $IOS_{MIN} = 2500\text{ mA}$.

$$IOS_{MIN} = \frac{48000}{R_{ILIMx}^{1.037}} = 2500\text{mA} \quad (5)$$

$$R_{ILIMx} = \left[\frac{48000}{IOS_{MIN}} \right]^{\frac{1}{1.037}} = \left[\frac{48000}{2500\text{mA}} \right]^{\frac{1}{1.037}} = 17.28\text{k}\Omega \quad (6)$$

Including resistor tolerance, target maximum:

$$R_{ILIMx} = \frac{17.28\text{k}\Omega}{1.01} = 17.11\text{k}\Omega \quad (7)$$

Choose:

$$R_{ILIMx} = 16.9\text{k}\Omega \quad (8)$$

Layout Guidelines

TPS2554/55 Placement: Place the TPS2554/55 near the USB output connector and 150- μF OUT pin filter capacitor. Connect the exposed PowerPad™ to the GND pin and to the system ground plane using a via array.

IN Pin Bypass Capacitance: Place the 100-nF bypass capacitor near the IN and GND pins, and make the connections using a low-inductance trace.

ILIM0 and ILIM1 Pin Connections: Current-limit, set-point accuracy can be compromised by stray current leakage from a higher voltage source to the ILIM0 or ILIM1 pins. Ensure that there is adequate spacing between IN pin copper/trace and ILIM0 pin trace to prevent contaminant buildup during the PCB assembly process. If a low-current-limit set point is required ($R_{ILIMx} > 200\text{ k}\Omega$), use ILIM1 for this case as it is further away from the IN pin.

Power Dissipation and Junction Temperature

The low on resistance of the N-channel MOSFET allows small surface-mount packages to pass large currents. It is good design practice to estimate power dissipation and junction temperature. The below analysis gives an approximation for calculating junction temperature based on the power dissipation in the package. However, it is important to note that thermal analysis is strongly dependent on additional system-level factors. Such factors include air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power. Good thermal-design practice must include all system-level factors in addition to individual component analysis.

Begin by determining the $R_{DS(on)}$ of the MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $R_{DS(on)}$ from the typical characteristics graph. Using this value, the power dissipation can be calculated by:

- $P_D = R_{DS(on)} \times I_{OUT}^2$

Where:

- P_D = Total power dissipation (W)
- $R_{DS(on)}$ = Power switch on-resistance (Ω)
- I_{OUT} = Maximum current-limit threshold (A)

This step calculates the total power dissipation of the MOSFET.

Finally, calculate the junction temperature:

- $T_J = P_D \times \theta_{JA} + T_A$

Where:

- T_A = Ambient temperature ($^{\circ}\text{C}$)
- θ_{JA} = Thermal resistance ($^{\circ}\text{C}/\text{W}$)
- P_D = Total power dissipation (W)

Compare the calculated junction temperature with the initial estimate. If they are not within a few degrees, repeat the calculation using a "refined" $R_{DS(on)}$ based on the calculated MOSFET temperature from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final junction temperature is highly dependent on thermal resistance θ_{JA} , and thermal resistance is highly dependent on the individual package and board layout.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TPS2554DRCR	ACTIVE	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2554DRCT	ACTIVE	SON	DRC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2555DRCR	ACTIVE	SON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
TPS2555DRCT	ACTIVE	SON	DRC	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2554DRCR	SON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS2554DRCT	SON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS2555DRCR	SON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS2555DRCT	SON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS

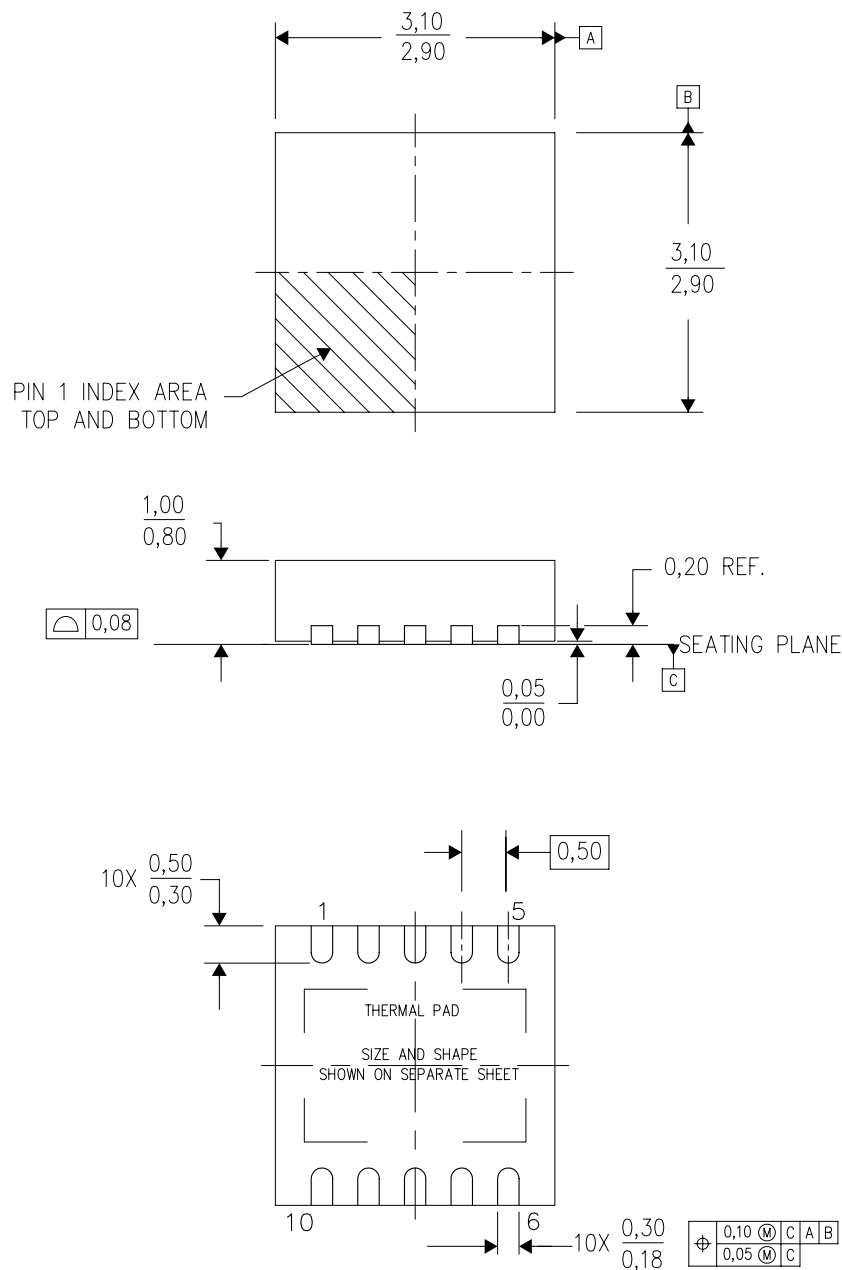


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2554DRCR	SON	DRC	10	3000	367.0	367.0	35.0
TPS2554DRCT	SON	DRC	10	250	210.0	185.0	35.0
TPS2555DRCR	SON	DRC	10	3000	367.0	367.0	35.0
TPS2555DRCT	SON	DRC	10	250	210.0	185.0	35.0

DRC (S-PVSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



4204102-3/L 09/11

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - Small Outline No-Lead (SON) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance, if present.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions, if present

DRC (S-PVSON-N10)

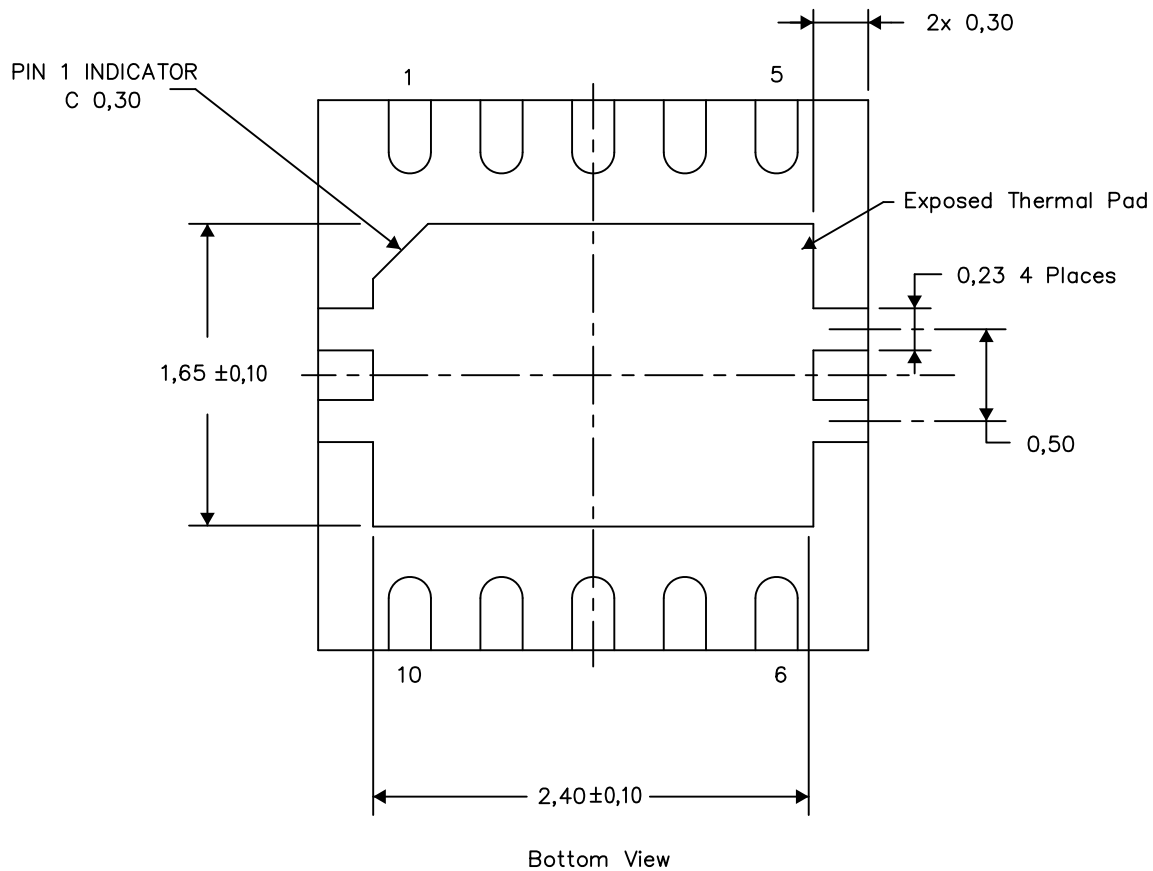
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



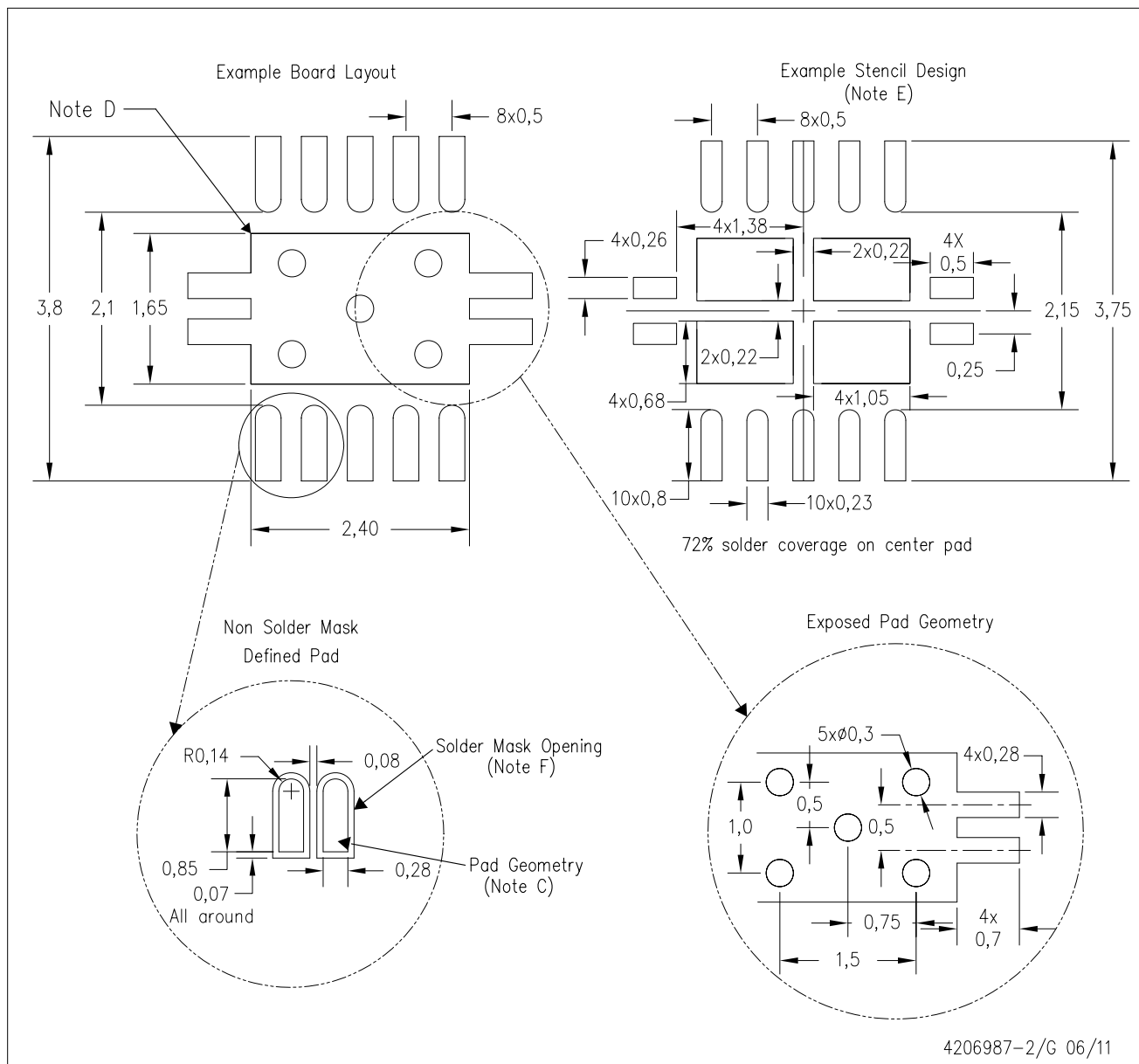
Exposed Thermal Pad Dimensions

4206565-3/N 07/12

NOTE: A. All linear dimensions are in millimeters

DRC (S-PVSON-N10)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

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